

# 3A, 50V - 1000V High Efficient Surface Mount Rectifier

### **FEATURES**

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- Low profile package
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer and telecommunication

### **MECHANICAL DATA**

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.210g (approximately)

KEY PARAMETERS				
PARAMETER VALUE UNIT				
١ <sub>F</sub>	3	А		
V <sub>RRM</sub>	50 - 1000	V		
I <sub>FSM</sub>	150	А		
T <sub>J MAX</sub>	150	°C		
Package	DO-214AB (SMC)			
Configuration	Single die			





DO-214AB (SMC)



<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)										
PARAMETER	SYMBOL	HS3A	HS3B	HS3D	HS3F	HS3G	HS3J	HS3K	HS3M	UNIT
Marking code on the device		HS3A	HS3B	HS3D	HS3F	HS3G	HS3J	HS3K	HS3M	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	210	280	420	560	700	V
Forward current	۱ <sub>۶</sub>	I <sub>F</sub> 3			А					
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	I <sub>FSM</sub> 150				A				
Junction temperature	T <sub>J</sub> - 55 to +150			°C						
Storage temperature	T <sub>STG</sub>	T <sub>STG</sub> - 55 to +150			°C					



THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-ambient thermal resistance	R <sub>eja</sub>	60	°C/W	

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
(1)	HS3A HS3B HS3D HS3F			-	1.0	V
Forward voltage <sup>(1)</sup>	HS3G	☐ I <sub>F</sub> = 3A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	1.3	V
	HS3J HS3K HS3M			-	1.7	V
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>		$T_J = 25^{\circ}C$		-	10	μA
		T <sub>J</sub> = 125°C	I <sub>R</sub>	-	250	μA
Junction capacitance	HS3A HS3B HS3D HS3F HS3G	1MHz, V <sub>R</sub> = 4.0V	CJ	80	-	pF
	HS3J HS3K HS3M			50	-	pF
Reverse recovery time	HS3A HS3B HS3D HS3F HS3G	I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A, I <sub>rr</sub> = 0.25A	t <sub>rr</sub>	-	50	ns
	HS3J HS3K HS3M			-	75	ns

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING		
HS3x	DO-214AB (SMC)	3,000 / Tape & Reel		

Notes:

1. "x" defines voltage from 50V(HS3A) to 1000V(HS3M)



1000

100

10

1

10

20

INSTANTANEOUS REVERSE CURRENT (µA)

## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

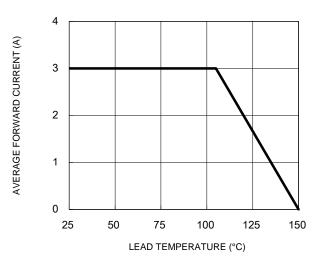
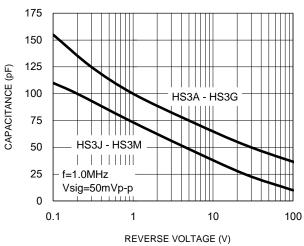


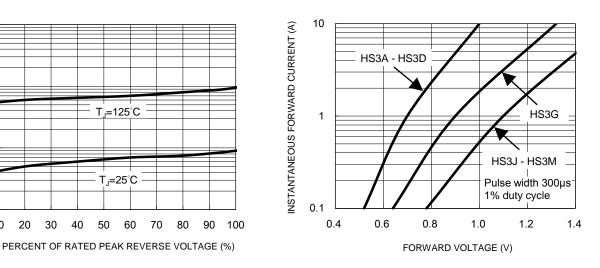
Fig.1 Forward Current Derating Curve

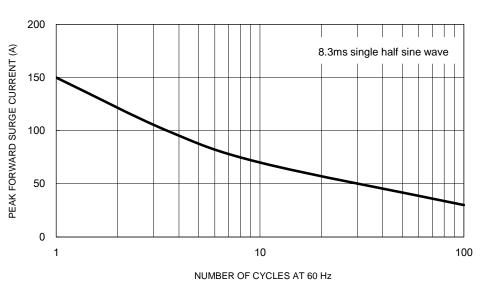
Fig.3 Typical Reverse Characteristics



**Fig.2 Typical Junction Capacitance** 







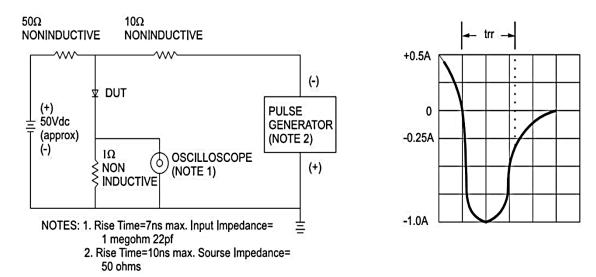
#### Fig.5 Maximum Non-Repetitive Forward Surge Current

Version: K2102



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

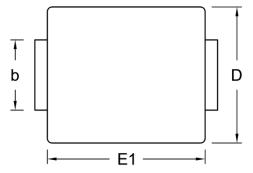


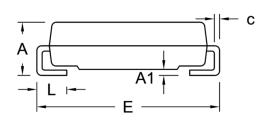
#### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



# PACKAGE OUTLINE DIMENSIONS

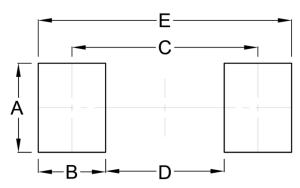
DO-214AB (SMC)





DIM. Un		(mm)	Unit (inch)		
	Min.	Max.	Min.	Max.	
A	2.00	2.62	0.079	0.103	
A1	0.10	0.20	0.004	0.008	
b	2.90	3.20	0.114	0.126	
с	0.15	0.31	0.006	0.012	
D	5.59	6.22	0.220	0.245	
E	7.75	8.13	0.305	0.320	
E1	6.60	7.11	0.260	0.280	
L	1.00	1.60	0.039	0.063	

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	3.30	0.130
В	2.50	0.098
С	6.90	0.272
D	4.40	0.173
E	9.40	0.370

## **MARKING DIAGRAM**



- P/N = Marking Code
- G = Green Compound

YW = Date Code

F = Factory Code



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